









SN74LV74A-Q1

SCLS556C - DECEMBER 2003 - REVISED AUGUST 2023

# SN74LV74A-Q1 Automotive Dual Positive-Edge-Triggered D-Type Flip-Flop

#### 1 Features

- Qualified for automotive applications
- Operation of 2-V to 5.5-V  $V_{CC}$
- Max t<sub>pd</sub> of 13 ns at 5 V
- Typical V<sub>OLP</sub> (output ground bounce) <0.8 V at V<sub>CC</sub>  $= 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) >2.3 V at  $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Support mixed-mode voltage operation on all ports
- I<sub>off</sub> supports partial-power-down mode operation
- Latch-up performance exceeds 250 mA per JESD

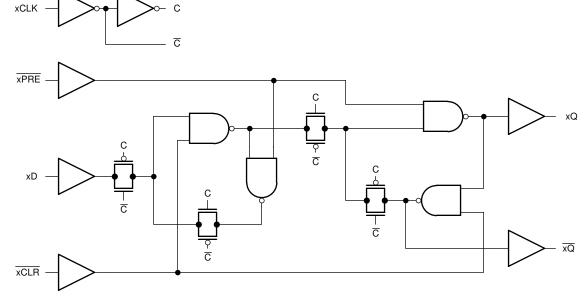
## 2 Description

This dual positive-edge-triggered D-type flip-flop is designed for 2-V to 5.5-V V<sub>CC</sub> operation.

#### **Package Information**

	1		
PART NUMBER	PACKAGE PACKAGE		
SN74LV74A-Q1	PW (TSSOP, 14)	5.00 mm × 6.4 mm	
	D (SOIC, 14)	8.65 mm x 6 mm	

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.



Logic Diagram, Each Flip-flop (Positive Logic)



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## 3 Revision History

## Changes from Revision B (April 2008) to Revision C (August 2023)

Page

 Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

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# **4 Pin Configuration and Functions**

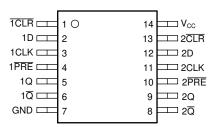


Figure 4-1. D and PW Package 14-Pin SOIC and TSSOP (Top View)

**Table 4-1. Pin Functions** 

PIN		TYPE1	DESCRIPTION
NO.	NAME	ITPE	DESCRIPTION
1	1 CLR	I	1 clear
2	1D	I	1D input
3	1CLK	I	1 clock
4	1 PRE	I	1 preset
5	1Q	0	1Q output
6	1 Q	0	1 Q output
7	GND	_	GND
8	2 Q	0	2 Q output
9	2Q	0	2Q output
10	2 PRE	I	2 preset
11	2CLK	I	2 clock
12	2D	I	2D input
13	2 CLR	I	2 clear
14	Vcc	_	Supply voltage input

1. Signal Types: I = Input, O = Output, I/O = Input or Output.



# **5 Specifications**

# 5.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
VI	Input voltage range <sup>(2)</sup>	out voltage range <sup>(2)</sup>		7	V
Vo	Voltage applied to any output in the h	/oltage applied to any output in the high-impedance or power-off state <sup>(2)</sup>		7	V
Vo	Output voltage range <sup>(2) (3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		<b>–</b> 50	mA
Io	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>	-25	25	mA
	Continuous current through V <sub>CC</sub> or GND		-50	50	mA
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 5.2 ESD Ratings

			VALUE	UNIT
V <sub>(Fab.)</sub> Electrostatic	Human-body model (HBM), per AEC Q100-002 <sup>1</sup>	±2000	V	
V <sub>(ESD)</sub>	discharge	Charged device model (CDM), per AEC Q100-011	±1000	V

<sup>(1)</sup> AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>1</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	V
		V <sub>CC</sub> = 2 V	1.5		
.,	Lligh level input valtage	V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> x 0.7		\/
VIH	Low-level input voltage  Input voltage  Output voltage  High-level output current	V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> x 0.7		V
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> x 0.7		
		V <sub>CC</sub> = 2 V		0.5	
V <sub>CC</sub> V <sub>IH</sub> V <sub>I</sub> V <sub>I</sub> V <sub>O</sub> I <sub>OH</sub>	Low level input veltage	V <sub>CC</sub> = 2.3 V to 2.7 V		V <sub>CC</sub> x 0.3	V V V μA mA
	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		V <sub>CC</sub> x 0.3	V
		V <sub>CC</sub> = 4.5 V to 5.5 V		V <sub>CC</sub> x 0.3	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V		-50	μΑ
1	High lovel output current	V <sub>CC</sub> = 2.3 V to 2.7 V		-2	
ОН	High-level input voltage  Low-level input voltage  Input voltage  Output voltage  High-level output current	V <sub>CC</sub> = 3 V to 3.6 V		-6	mA
		V <sub>CC</sub> = 4.5 V to 5.5 V		-12	
		V <sub>CC</sub> = 2 V		50	μA
	Low lovel output ourrent	$V_{CC}$ = 2.3 V to 2.7 V		2	
OL	Low-level output current	V <sub>CC</sub> = 3 V to 3.6 V		6	mA
		V <sub>CC</sub> = 4.5 V to 5.5 V		12	

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<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The value is limited to 5.5-V maximum.

over operating free-air temperature range (unless otherwise noted)<sup>1</sup>

	-		MIN	MAX	UNIT
	V <sub>CC</sub> = 2.3 V to 2.7 V		200		
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 3 V to 3.6 V		100	ns/V
		V <sub>CC</sub> = 4.5 V to 5.5 V		20	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

#### 5.4 Thermal Information

over operating free-air temperature range (unless otherwise noted)

THERMAL METRIC(1)		D	PW	UNIT
	THERMAL METRIC	14 PINS	14 PINS	ONT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	113	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

#### 5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
V		I <sub>OH</sub> = -50 μA	2 to 5.5 V	V <sub>CC</sub> - 0.1			
	High level output voltage	I <sub>OH</sub> = -2 mA	2.3 V	2			V
V <sub>OH</sub>	r ligit level output voltage	I <sub>OH</sub> = -6 mA	3 V	2.48			V
		I <sub>OH</sub> = -12 mA	4.5 V	3.8			
		I <sub>OL</sub> = 50 μA	2 to 5.5 V			0.1	
\ <u>\</u>	Low level output voltage	I <sub>OL</sub> = 2 mA	2.3 V			0.4	V
V <sub>OL</sub>		I <sub>OL</sub> = 6 mA	3 V			0.44	V
		I <sub>OL</sub> = 12 mA	4.5 V			0.55	
I <sub>I</sub>	Input leakage current	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V			±1	μΑ
I <sub>CC</sub>	Supply current	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20	μΑ
I <sub>off</sub>	Input/Output Power-Off Leakage Current	$V_I$ or $V_O = 0$ to 5.5 V	0			5	μΑ
C	Innut Consoitance	V = V or CND	3.3 V		2		nE
Ci	C <sub>i</sub> Input Capacitance	$V_I = V_{CC}$ or GND	5 V		2		pF

# 5.6 Timing Requirements, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range,  $V_{CC}$  = 2.5 V ±0.2 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	ge marene,						
	PARAMETER		T <sub>A</sub> = 25°C		MIN MA		UNIT
	PARAMETER		MIN	MAX	IVIIIN	MAX	UNII
t <sub>w</sub> Pulse duration	PRE or CLR low	8		9		no	
I <sub>W</sub>	ruise duration	CLK	8		9		ns
	Setup time before CLK↑	Data	8		9		no
t <sub>su</sub> Setup	PRE or CLR low		7		7		ns
t <sub>h</sub>	Hold time, data after CLK↑		0.5		0.5		ns

## 5.7 Timing Requirements, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V ±0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	PARAMETER				MIN	MAX	UNIT
	PARAMETER		MIN	MAX	IVIIIN	IVIAA	UNIT
A Dulan dissation	PRE or CLR low	6		7			
ı <sub>w</sub>	Pulse duration	CLK	6		7		ns
	Saturatima hafara CLIVA	Data	6		7		
t <sub>su</sub>	Setup time before CLK↑	PRE or CLR low	5		5		ns
t <sub>h</sub>	Hold time, data after CLK↑		0.5		0.5		ns

# 5.8 Timing Requirements, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$

over recommended operating free-air temperature range,  $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$  (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	PARAMETER		T <sub>A</sub> = 25°C		T <sub>A</sub> = 25°C		T <sub>A</sub> = 25°C		MIN	MAY	UNIT
	PARAMETER		MIN	MAX	IVIIIN	WAX	UNII				
t <sub>w</sub> Pulse duration	PRE or CLR low	5		5		ns					
	Pulse duration	CLK	5		5		115				
	Setup time before CLK↑	Data	5		5		no				
t <sub>su</sub>	Setup time before CLK†	PRE or CLR low	3		3		ns				
t <sub>h</sub>	Hold time, data after CLK↑		0.5		0.5		ns				

## 5.9 Switching Characteristics, V<sub>CC</sub> = 2.5 V ±0.2 V

over recommended operating free-air temperature range,  $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

remage marener									
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	Т,	<sub>λ</sub> = 25°C		MIN	MAX	UNIT
	FROW (INFOT)	10 (001701)	CAPACITANCE	MIN	TYP	MAX		UNII	
f <sub>max</sub>			C <sub>L</sub> = 50 pF	30	70		25		MH <sub>Z</sub>
	PRE or CLR	Q or $\overline{\mathbb{Q}}$	0 - 50 - 5		13	17.4	1	20	ns
<sup>L</sup> pd	CLK	QuQ	$C_L = 50 \text{ pF}$		14.2	20	1	23	115

## 5.10 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V ±0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	то (оитрит)	LOAD	T <sub>A</sub> = 25°C			MIN MAX	MAY	UNIT
			CAPACITANCE	MIN	TYP	MAX	IVIIIA	IVIAA	ONIT
f <sub>max</sub>			C <sub>L</sub> = 50 pF	50	90		45		MHZ
	PRE or CLR	Q or $\overline{\mathbb{Q}}$	C = 50 pE		9.2	15.8	1	18	no
t <sub>pd</sub> (	CLK	QUIQ	C <sub>L</sub> = 50 pF		10.2	15.4	1	18	ns

## 5.11 Switching Characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ±0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	T	√ = 25°C			MAX	UNIT	
PARAMETER	FROM (INFOT)	10 (001701)	CAPACITANCE	MIN	TYP	MAX	IVIIIN	IVIAA	UNIT	
f <sub>max</sub>			C <sub>L</sub> = 50 pF	90	140		75		MHZ	
+	PRE or CLR	Q or $\overline{\mathbb{Q}}$	0.07 0.07 0.07 0.07		6.6	9.7	1	12	no	
T <sub>pd</sub>	CLK	QuiQ	C <sub>L</sub> = 50 pF		7.2	9.3	1	13	ns	

## **5.12 Noise Characteristics**

 $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$ 

	PARAMETER	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.1	0.8	
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		0	-0.8	
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		3.2		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.31			
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	

<sup>(1)</sup> Characteristics are for surface-mount packages only.

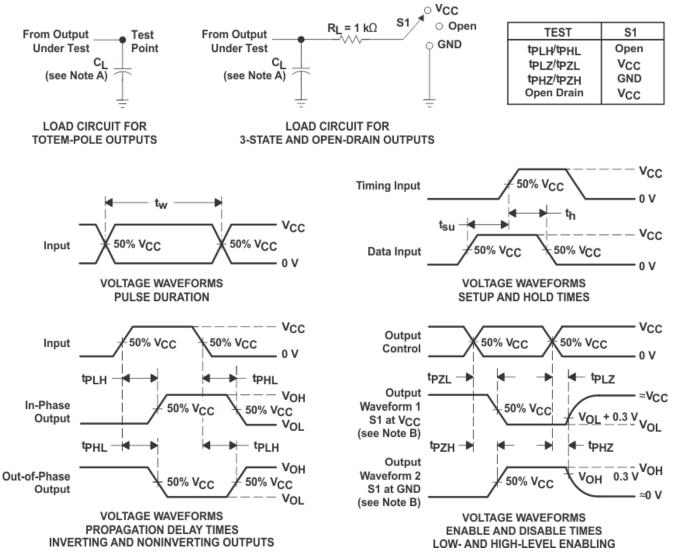
# **5.13 Operating Characteristics**

T<sub>A</sub> = 25°C

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
C <sub>nd</sub> Power dissipation capacitance	C <sub>1</sub> = 50 pF, f = 10 MHz	3.3 V	21	nE
C <sub>pd</sub> Fower dissipation capacitance	C <sub>L</sub> = 50 pr, t = 10 MHZ	5 V	23	p⊦



### **6 Parameter Measurement Information**



- C<sub>1</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 3$  ns.  $t_f \leq 3$  ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and tPZH are the same as  $t_{en}$ .
- G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms

## 7 Detailed Description

## 7.1 Overview

This dual positive-edge-triggered D-type flip-flop is designed for 2-V to 5.5-V V<sub>CC</sub> operation.

A low level at the preset  $(\overline{PRE})$  or clear  $(\overline{CLR})$  inputs sets or resets the outputs, regardless of the levels of the other inputs. When  $\overline{PRE}$  and  $\overline{CLR}$  are inactive (high), data at the data (D) inputs meeting the setup-time requirements is transferred to the outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### 7.2 Functional Block Diagram

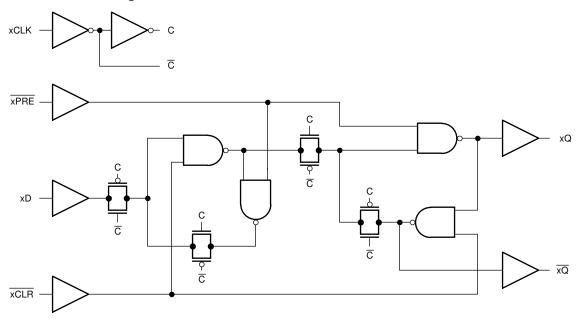


Figure 7-1. Logic Diagram, Each Flip-flop (Positive Logic)

#### 7.3 Device Functional Modes

**Table 7-1. Function Table** 

	INPUT	OUTPUTS <sup>(2)</sup>			
PRE	CLR	CLK	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	X	Χ	L	Н
L	L	X	X	H <sup>(3)</sup>	H <sup>(3)</sup>
Н	Н	<b>↑</b>	Н	Н	L
Н	Н	<b>↑</b>	L	L	Н
Н	Н	L	X	$Q_0$	$\overline{Q}_0$

- (1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low, Z = High Impedance State
- (3) This configuration is nonstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.



## **8 Device and Documentation Support**

## 8.1 Documentation Support

#### 8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LV74A-Q	1 Click here	Click here	Click here	Click here	Click here

# 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 8.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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## 8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74LV74AQDRG4Q1	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A
SN74LV74AQDRG4Q1.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A
SN74LV74AQDRQ1	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A
SN74LV74AQDRQ1.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A
SN74LV74AQPWRG4Q1	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A
SN74LV74AQPWRG4Q1.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# PACKAGE OPTION ADDENDUM

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#### OTHER QUALIFIED VERSIONS OF SN74LV74A-Q1:

● Enhanced Product : SN74LV74A-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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